



N-Channel NexFET™ Power MOSFETs

FEATURES

- Ultra Low Q_q and Q_{qd}
- Low Thermal Resistance
- Avalanche Rated
- · Pb Free Terminal Plating
- RoHS Compliant
- Halogen Free
- SON 5mm x 6mm Plastic Package

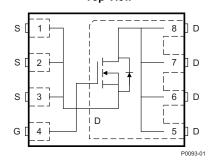
APPLICATIONS

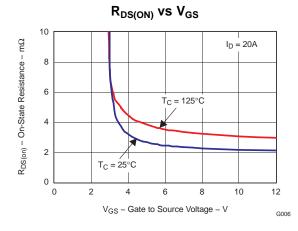
- Point-of-Load Synchronous Buck Converter for Applications in Networking, Telecom and Computing Systems
- Optimized for Control FET Applications

DESCRIPTION

The NexFET™ power MOSFET has been designed to minimize losses in power conversion applications.







PRODUCT SUMMARY

V _{DS}	Drain to Source Voltage	25	V	
Q_g	Gate Charge Total (4.5V)	13.3	nC	
Q_{gd}	Gate Charge Gate to Drain	3.5	nC	
D	Drain to Source On Resistance	$V_{GS} = 4.5V$	2.9	mΩ
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = 10V	2.2	mΩ
V _{GS(th)}	Threshold Voltage	1.6	V	

ORDERING INFORMATION

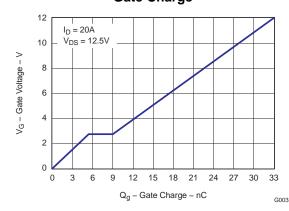
Device	Package	Media	Qty	Ship
CSD16403Q5A	SON 5X6 Plastic Package	13-inch reel	2500	Tape and Reel

ABSOLUTE MAXIMUM RATINGS

T _A = 2	5°C unless otherwise stated	VALUE	UNIT
V_{DS}	Drain to Source Voltage	25	٧
V_{GS}	Gate to Source Voltage	+16 / -12	٧
	Continuous Drain Current, T _C = 25°C	100	Α
I _D	Continuous Drain Current ⁽¹⁾	28	Α
I _{DM}	Pulsed Drain Current, T _A = 25°C ⁽²⁾	184	Α
P_D	Power Dissipation ⁽¹⁾	3.1	W
T _J , T _{STG}	Operating Junction and Storage Temperature Range	-55 to 150	°C
E _{AS}	Avalanche Energy, single pulse $I_D = 67A$, $L = 0.1 mH$, $R_G = 25 \Omega$	224	mJ

- (1) $R_{\theta JA} = 41^{\circ}\text{C/W}$ on 1in^2 Cu FR4 PCB.
- (2) Pulse width ≤300μs, duty cycle ≤2%

Gate Charge



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ELECTRICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

PARAMETER		PARAMETER TEST CONDITIONS				UNIT
Static Cl	haracteristics				·	
BV _{DSS}	Drain to Source Voltage	$V_{GS} = 0V, I_D = 250\mu A$	25			V
I _{DSS}	Drain to Source Leakage Current	$V_{GS} = 0V$, $V_{DS} = 20V$			1	μΑ
I _{GSS}	Gate to Source Leakage Current	$V_{DS} = 0V, V_{GS} = +16/-12V$			100	nA
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	1.2	1.6	1.9	V
D	Drain to Source On Registeres	$V_{GS} = 4.5V, I_D = 20A$		2.9	3.7	mΩ
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = 10V, I _D = 20A		2.2	2.8	mΩ
g _{fs}	Transconductance	V _{DS} = 15V, I _D = 20A		91		S
Dynamic	Characteristics		•			
C _{ISS}	Input Capacitance			2040	2660	pF
Coss	Output Capacitance	V _{GS} = 0V, V _{DS} = 12.5V , f = 1MHz		1600	2080	pF
C _{RSS}	Reverse Transfer Capacitance			115	160	pF
R _g	Series Gate Resistance			1.2	2.4	Ω
Qg	Gate Charge Total (4.5V)			13.3	18	nC
Q _{gd}	Gate Charge Gate to Drain	V 42 EV 1 20A		3.5		nC
Q _{gs}	Gate Charge Gate to Source	$V_{DS} = 12.5V, I_{D} = 20A$		5.5		nC
Qg(th)	Gate Charge at Vth			3.1		nC
Q _{OSS}	Output Charge	$V_{DS} = 13.5V, V_{GS} = 0V$		33		nC
t _{d(on)}	Turn On Delay Time			11.8		ns
t _r	Rise Time	$V_{DS} = 12.5V, V_{GS} = 4.5V, I_{D} = 20A,$		18.3		ns
t _{d(off)}	Turn Off Delay Time	$R_G = 2\Omega$		15.2		ns
t _f	Fall Time			9.2		ns
Diode C	haracteristics					
V _{SD}	Diode Forward Voltage	I _S = 20A, V _{GS} = 0V		0.8	1.0	V
Q _{rr}	Reverse Recovery Charge	$V_{DD} = 13.5V$, $I_F = 20A$, $di/dt = 300A/\mu s$		47		nC
t _{rr}	Reverse Recovery Time	$V_{DD} = 13.5V$, $I_F = 20A$, $di/dt = 300A/\mu s$		35		ns

THERMAL CHARACTERISTICS

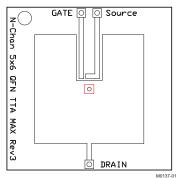
 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

	PARAMETER	MIN	TYP	MAX	UNIT
R _{θJC}	Thermal Resistance Junction to Case (1)			1.8	°C/W
R _{θJA}	Thermal Resistance Junction to Ambient ⁽¹⁾⁽²⁾			51	°C/W

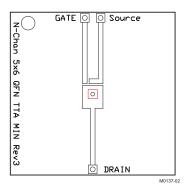
⁽¹⁾ $R_{\theta JC}$ is determined with the device mounted on a 1 inch square 2 oz. Cu pad on a 1.5 x 1.5 in 0.060 inch thick FR4 board. $R_{\theta JC}$ is specified by design while $R_{\theta JA}$ is determined by the user's board design.

⁽²⁾ Device mounted on FR4 Material with 1 inch² of 2 oz. Cu.





Max $R_{\theta JA} = 51^{\circ}C/W$ when mounted on 1 inch² of 2 oz. Cu.



Max $R_{\theta JA} = 118^{\circ}C/W$ when mounted on minimum pad area of 2 oz. Cu.

TYPICAL MOSFET CHARACTERISTICS

(T_A = 25°C unless otherwise stated)

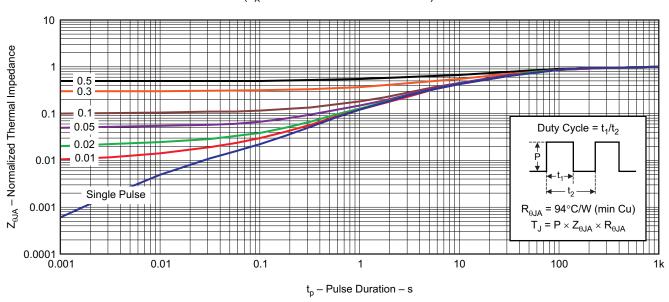


Figure 1. Transient Thermal Impedance

G012

TEXAS INSTRUMENTS

TYPICAL MOSFET CHARACTERISTICS (continued)

(T_A = 25°C unless otherwise stated)

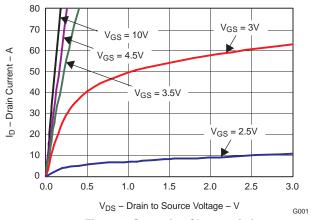


Figure 2. Saturation Characteristics

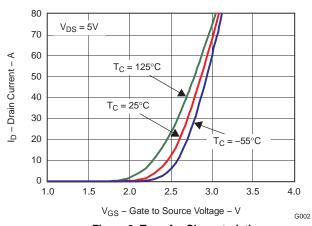


Figure 3. Transfer Characteristics

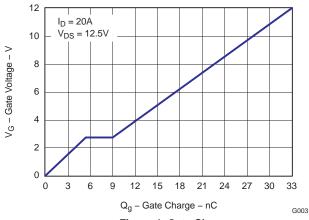
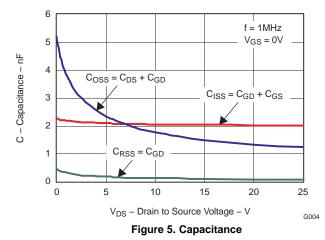


Figure 4. Gate Charge



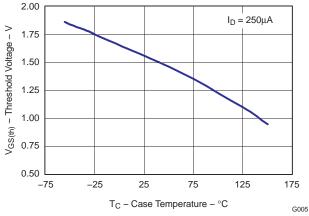


Figure 6. Threshold Voltage vs Temperature

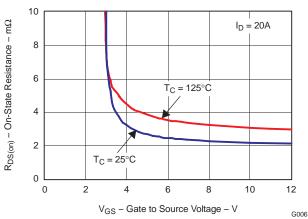


Figure 7. On Resistance vs Gate Voltage

TYPICAL MOSFET CHARACTERISTICS (continued)

(T_A = 25°C unless otherwise stated)

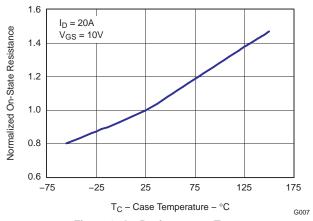


Figure 8. On Resistance vs Temperature

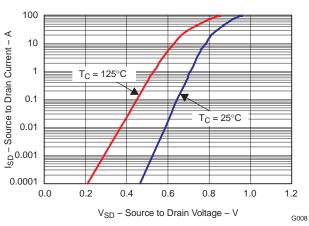


Figure 9. Typical Diode Forward Voltage

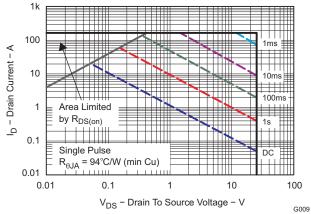


Figure 10. Maximum Safe Operating Area

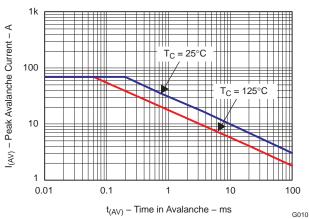


Figure 11. Single Pulse Unclamped Inductive Switching

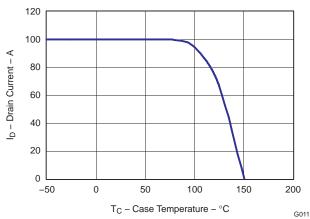
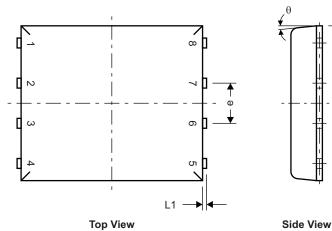


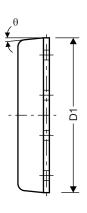
Figure 12. Maximum Drain Current vs Temperature

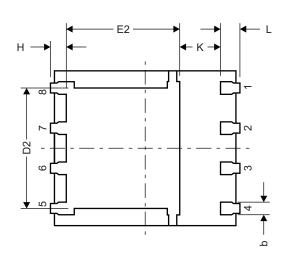


MECHANICAL DATA

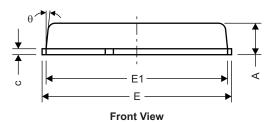
Q5A Package Dimensions







Bottom View

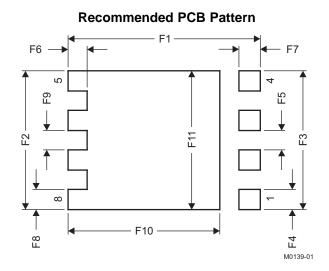


M0135-01

DIM		MILLIMETERS	
	MIN	NOM	MAX
Α	0.90	1.00	1.10
b	0.33	0.41	0.51
С	0.20	0.25	0.30
D1	4.80	4.90	5.00
D2	3.61	3.81	3.96
E	5.90	6.00	6.10
E1	5.70	5.75	5.80
E2	3.38	3.58	3.78
е		1.27 BSC	
Н	0.41	0.51	0.61
K	1.10		
L	0.51 0.61		0.71
L1	0.06	0.06 0.13	
θ	0°		12°

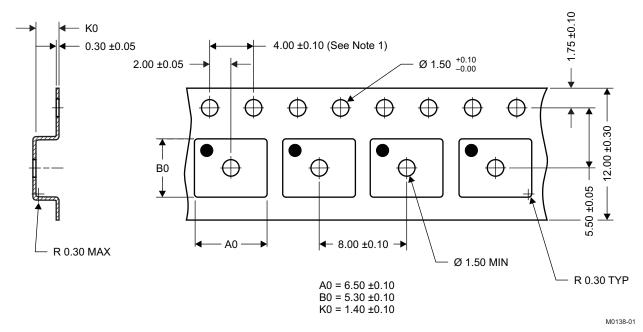
For recommended circuit layout for PCB designs, see application note SLPA005 - Reducing Ringing Through PCB Layout Techniques.





DIM	MILLIM	IETERS	INC	HES
DIN	MIN	MAX	MIN	MAX
F1	6.205	6.305	0.244	0.248
F2	4.46	4.56	0.176	0.18
F3	4.46	4.56	0.176	0.18
F4	0.65	0.7	0.026	0.028
F5	0.62	0.67	0.024	0.026
F6	0.63	0.68	0.025	0.027
F7	0.7	0.8	0.028	0.031
F8	0.65	0.7	0.026	0.028
F9	0.62	0.67	0.024	0.026
F10	4.9	5	0.193	0.197
F11	4.46	4.56	0.176	0.18

Q5A Tape and Reel Information



Notes:

- 1. 10 sprocket hole pitch cumulative tolerance ±0.2
- 2. Camber not to exceed 1mm IN 100mm, noncumulative over 250mm
- 3. Material:black static dissipative polystyrene
- 4. All dimensions are in mm (unless otherwise specified)
- 5. A0 and B0 measured on a plane 0.3mm above the bottom of the pocket
- 6. MSL1 260°C (IR and Convection) PbF Reflow Compatible



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Package Marking Information

Location

1st Line

CSD = Fixed Characters
NNNNN = Product Code

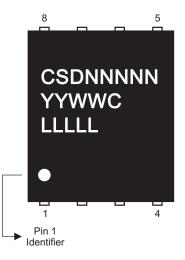
2nd Line (Date Code)

YY = Last 2 digits of the Year
WW = 2-digit Work Week
C = Country of Origin
> Philippines = P

> Taiwan = T > China = C

3rd Line

LLLLL = Last 5 digits of the Wafer Lot #





M0136-01

Submit Documentation Feedback



PACKAGE OPTION ADDENDUM

www.ti.com 1-Feb-2010

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins Pa	ackage Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
CSD16403Q5A	ACTIVE	SON	DQJ	8	2500	Pb-Free (RoHS Exempt)	CU SN	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD16403Q5A	SON	DQJ	8	2500	330.2	12.4	6.5	5.3	1.4	8.0	12.0	Q1

PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CSD16403Q5A	SON	DQJ	8	2500	347.0	342.0	55.0

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		Wireless	www.ti.com/wireless-apps